



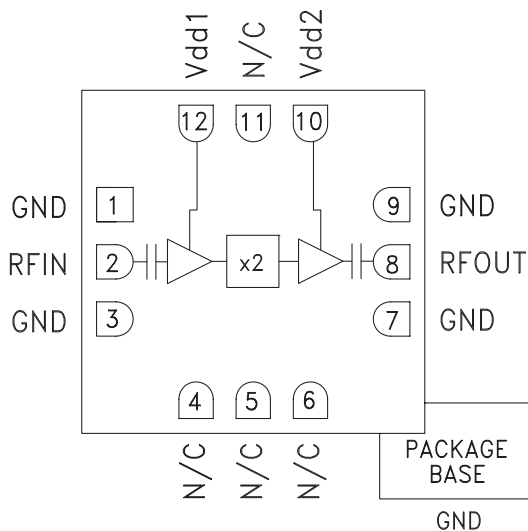
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT

Typical Applications

The HMC576LC3B is suitable for:

- Clock Generation Applications:
SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

- High Output Power: +15 dBm
- Low Input Power Drive: 0 to +6 dBm
- Fo Isolation: >20 dBc @ Fout= 24 GHz
- 100 KHz SSB Phase Noise: -132 dBc/Hz
- Single Supply: +5V@ 82 mA
- RoHS Compliant 3x3 mm SMT Package

General Description

The HMC576LC3B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +3 dBm signal, the multiplier provides +15 dBm typical output power from 18 to 29 GHz. The Fo and 3Fo isolations are >20 dBc at 24 GHz. The HMC576LC3B is ideal for use in LO multiplier chains for Pt to Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -132 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC576LC3B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ C$, $V_{dd1}, V_{dd2} = +5V$, 3 dBm Drive Level

| Parameter | Min. | Typ. | Max. | Units |
|---|----------|------|------|--------|
| Frequency Range, Input | 9 - 14.5 | | | GHz |
| Frequency Range, Output | 18 - 29 | | | GHz |
| Output Power | 10 | 15 | | dBm |
| Fo Isolation (with respect to output level) | 20 | | | dBc |
| 3Fo Isolation (with respect to output level) | 20 | | | dBc |
| Input Return Loss | 10 | | | dB |
| Output Return Loss | 10 | | | dB |
| SSB Phase Noise (100 kHz Offset) | -132 | | | dBc/Hz |
| Supply Current (I _{dd1} & I _{dd2}) | 82 | | | mA |

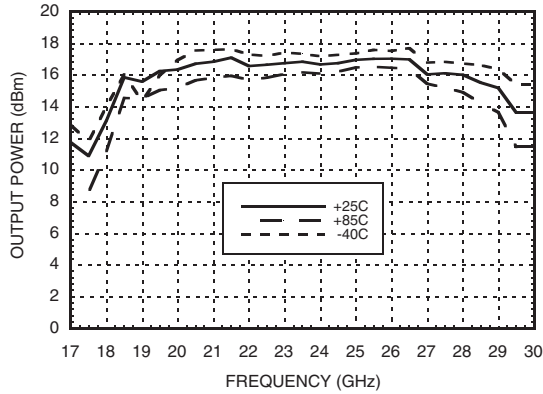
For price, delivery, and to place orders, please contact Hittite Microwave Corporation:

SUNSTAR 微波光电 <http://www.hittite.com> / TEL:0755-83396822 FAX:0755-83376182 E-MAIL: szss20@163.com
Order On-line at www.hittite.com

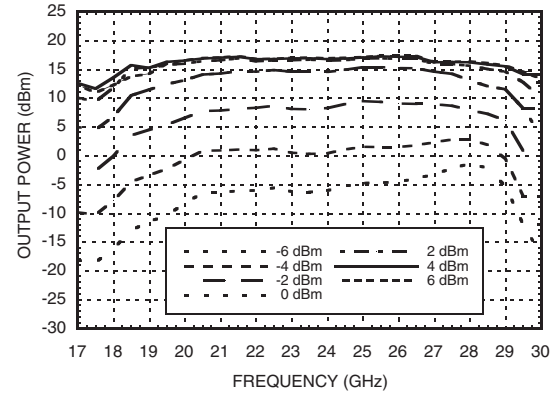
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT



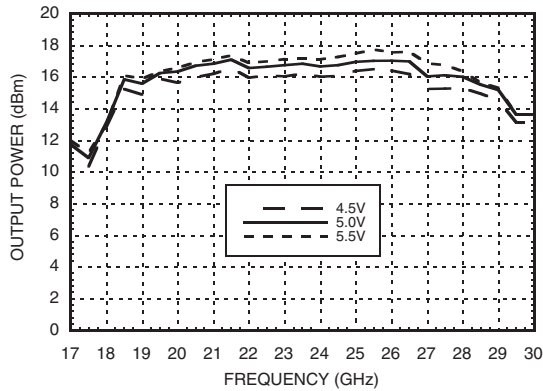
Output Power vs. Temperature @ 3 dBm Drive Level



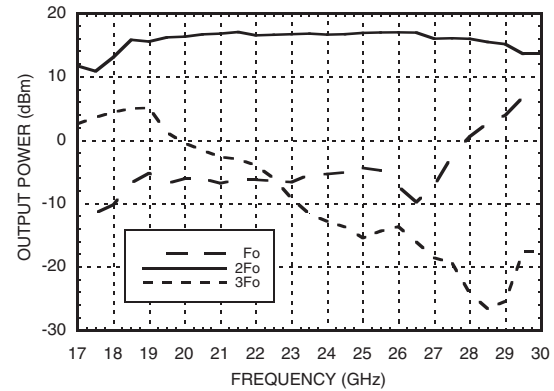
Output Power vs. Drive Level



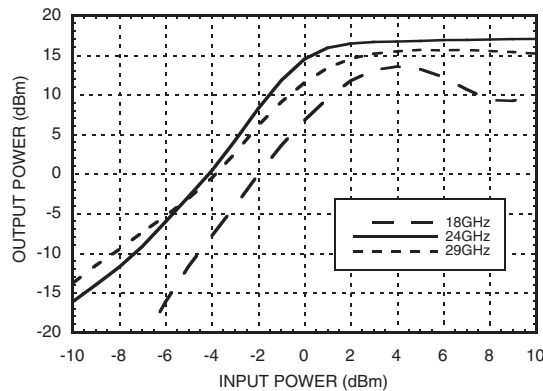
Output Power vs. Supply Voltage @ 3 dBm Drive Level



Isolation @ 3 dBm Drive Level



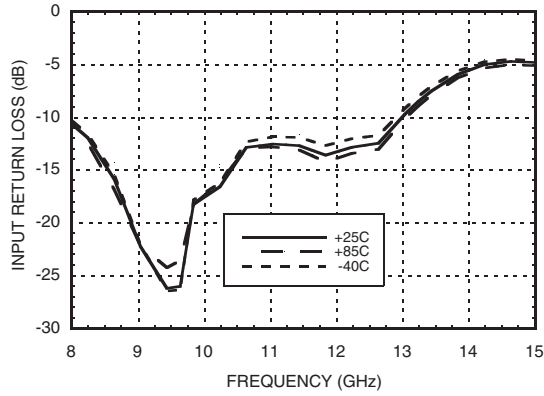
Output Power vs. Input Power



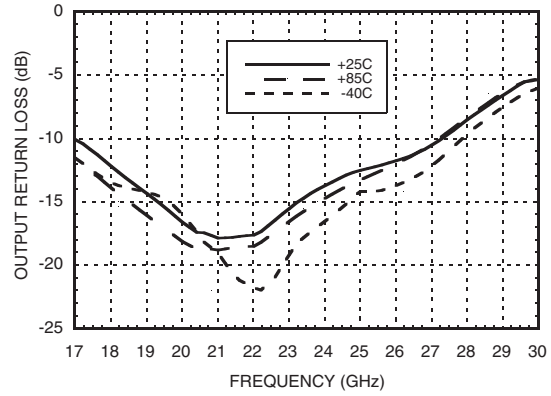


SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT

Input Return Loss vs. Temperature



Output Return Loss vs. Temperature





SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT

Absolute Maximum Ratings

| | |
|---|----------------|
| RF Input (Vdd = +5V) | +13 dBm |
| Supply Voltage (Vdd) | +6.0 Vdc |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T= 85 °C) (derate 7.5 mW/°C above 85 °C) | 676 mW |
| Thermal Resistance (channel to ground paddle) | 133 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |

Typical Supply Current vs. Vdd

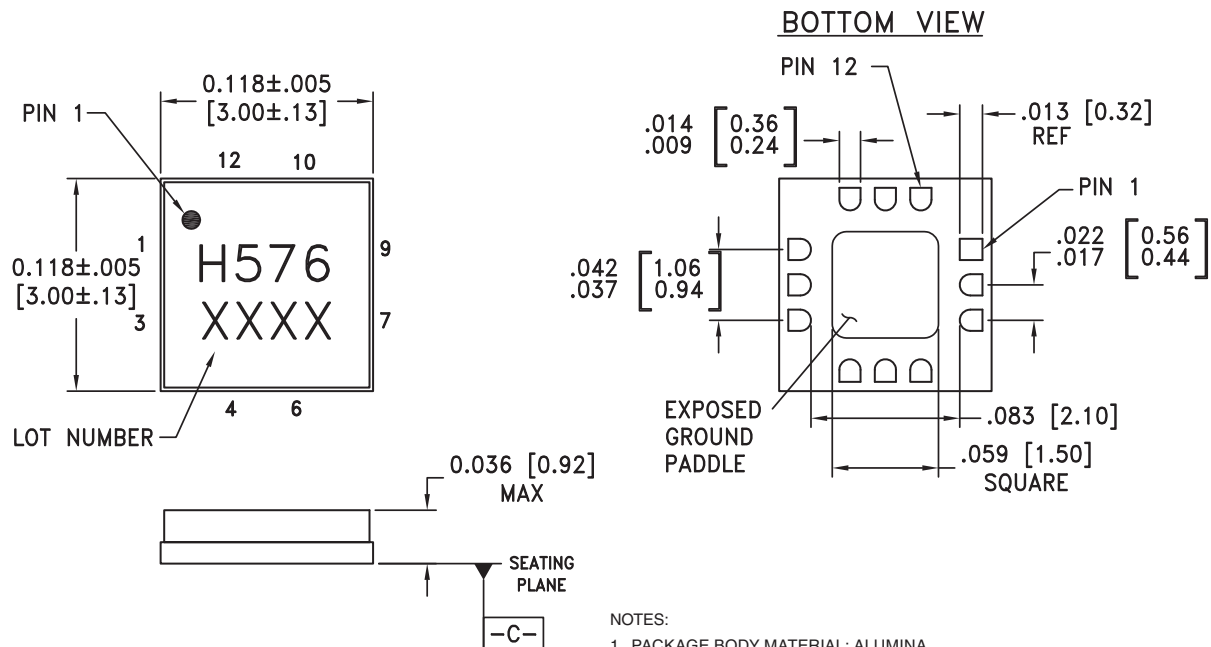
| Vdd (Vdc) | Idd (mA) |
|-----------|----------|
| 4.5 | 82 |
| 5.0 | 82 |
| 5.5 | 83 |

Note:
Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing




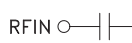
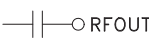
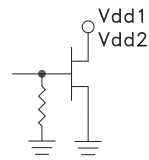
NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM **-C-**
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.



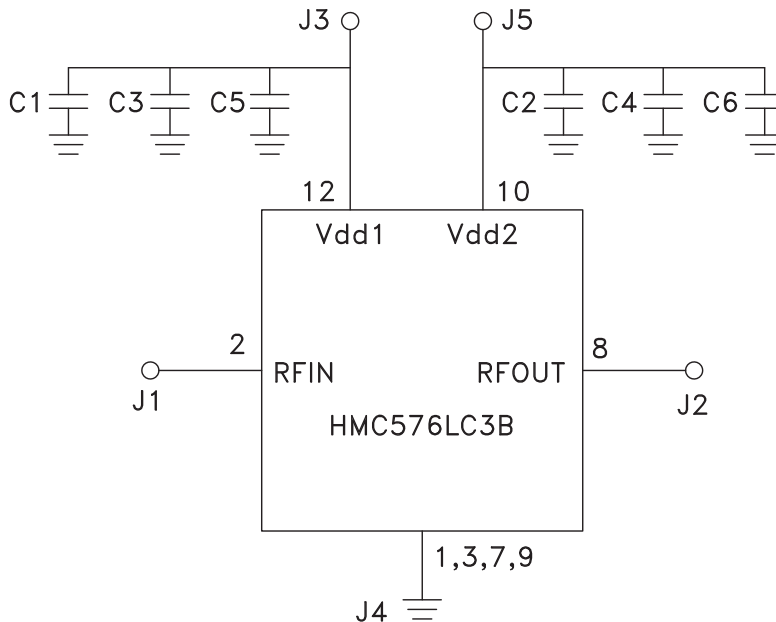
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT

Pin Description

| Pin Number | Function | Description | Interface Schematic |
|------------|------------|---|---|
| 1, 3, 7, 9 | GND | Package bottom must also be connected to RF/DC ground. |  |
| 2 | RFIN | Pin is AC coupled and matched to 50 Ohms. |  |
| 4 - 6, 11 | N/C | These pins are internally not connected; however, this product was specified with these pins connected to RF/DC ground. | |
| 8 | RFOUT | Pin is AC coupled and matched to 50 Ohms. |  |
| 10, 12 | Vdd2, Vdd1 | Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required. |  |

Application Circuit

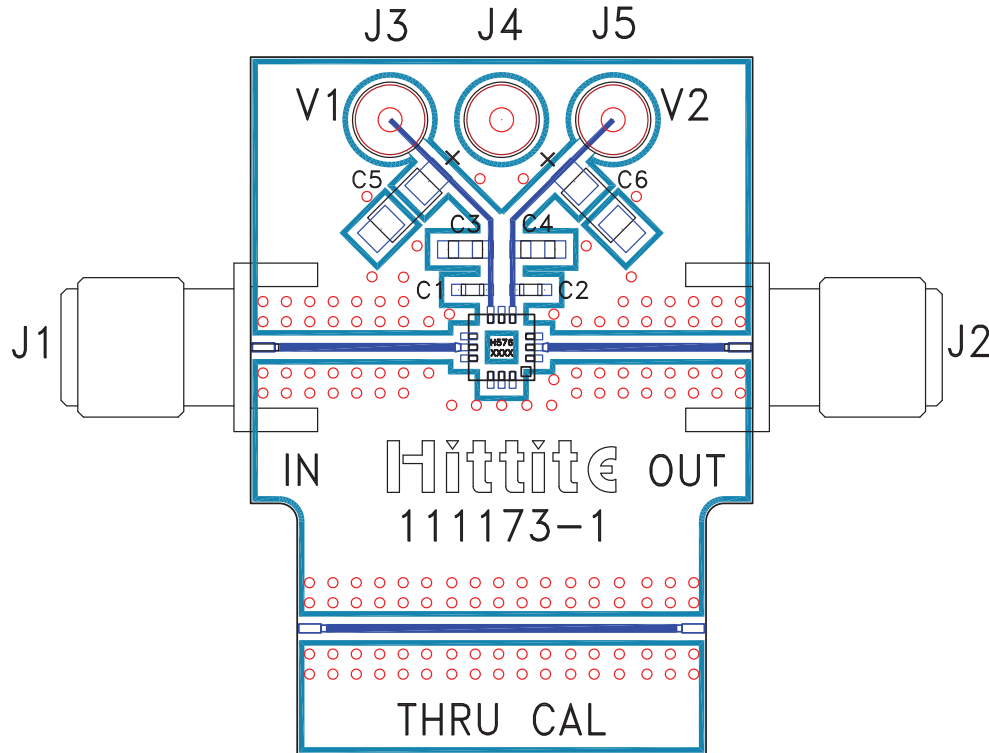
| Component | Value |
|-----------|----------|
| C1, C2 | 100 pF |
| C3, C4 | 1,000 pF |
| C5, C6 | 2.2 μF |



SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 18 - 29 GHz OUTPUT



Evaluation PCB



List of Materials for Evaluation PCB 112409 [1]

| Item | Description |
|---------|---------------------------------|
| J1, J2 | PCB Mount SRI K Connector |
| J3 - J5 | DC Pin |
| C1, C2 | 100 pF Capacitor, 0402 Pkg. |
| C3, C4 | 1,000 pF Capacitor, 0603 Pkg. |
| C5, C6 | 2.2 μ F Tantalum Capacitor |
| U1 | HMC576LC3B x2 Active Multiplier |
| PCB [2] | 111173 Eval Board |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.